

TLV2780, TLV2781, TLV2782, TLV2783, TLV2784, TLV2785, TLV278xA FAMILY OF 1.8 V HIGH-SPEED RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

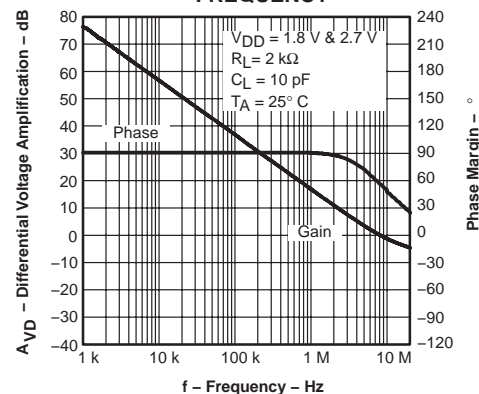
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- Supply Voltage Range . . . 1.8 V to 3.6 V
- Rail-to-Rail Input/Output
- High Bandwidth . . . 8 MHz
- High Slew Rate . . . 4.8 V/ μ s
- V_{ICR} Exceeds Rails . . . -0.2 V to $V_{DD} + 0.2$
- Supply Current . . . 650 μ A/Channel
- Input Noise Voltage . . . 9 nV/ $\sqrt{\text{Hz}}$ at 10 kHz
- Specified Temperature Range:
0°C to 70°C . . . Commercial Grade
-40°C to 125°C . . . Industrial Grade
- Ultrasmall Packaging
- Universal Operational Amplifier EVM

Operational Amplifier



DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE VS FREQUENCY



description

The TLV278x single supply operational amplifiers provide rail-to-rail input and output capability. The TLV278x takes the minimum operating supply voltage down to 1.8 V over the extended industrial temperature range (-40°C to 125°C) while adding the rail-to-rail output swing feature. The TLV278x also provides 8 MHz bandwidth from only 650 μ A of supply current. The maximum recommended supply voltage is 3.6 V, which allows the devices to be operated from (± 1.8 V supplies down to ± 0.9 V) two rechargeable cells.

The combination of wide bandwidth, low noise, and low distortion makes it ideal for high speed and high resolution data converter applications.

All members are available in PDIP, SOIC, and the newer, smaller SOT-23 (singles), MSOP (duals), and TSSOP (quads).

FAMILY PACKAGE TABLE

| DEVICE | V_{DD} [V] | V_{IO} [μ V] | I_{DD}/ch [μ A] | I_{IB} [pA] | GBW [MHz] | SLEW RATE [V/ μ s] | V_n , 1 kHz [nV/ $\sqrt{\text{Hz}}$] | I_O [mA] | SHUTDOWN | RAIL-TO-RAIL |
|------------|-----------------|------------------------|----------------------------------|------------------|--------------|---------------------------|--|---------------|----------|--------------|
| TLV278x(A) | 1.8–3.6 | 250 | 650 | 2.5 | 8 | 5 | 18 | 10 | Y | I/O |
| TLV276x(A) | 1.8–3.6 | 550 | 20 | 3 | 0.5 | 0.23 | 95 | 5 | Y | I/O |
| TLV246x(A) | 2.7–6 | 150 | 550 | 1300 | 6.4 | 1.6 | 11 | 25 | Y | I/O |
| TLV247x(A) | 2.7–6 | 250 | 600 | 2.5 | 2.8 | 1.5 | 15 | 20 | Y | I/O |
| TLV244x(A) | 2.7–10 | 300 | 750 | 1 | 1.81 | 1.4 | 16 | 2 | — | O |
| TLV277x(A) | 2.5–5.5 | 360 | 1000 | 2 | 5.1 | 10.5 | 17 | 6 | Y | O |



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

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TLV2780 and TLV2781 AVAILABLE OPTIONS(1)

| T _A | V _{IOmax} AT 25°C | PACKAGED DEVICES | | | |
|----------------|-------------------------------|--------------------------|----------------------------|--------------|------------------------|
| | | SMALL OUTLINE (D)† | SOT-23 | | PLASTIC DIP (P) |
| | | | (DBV)‡ | SYMBOL | |
| 0°C to 70°C | 3000 μV | TLV2780CD TLV2781CD | TLV2780CDBV TLV2781CDBV | VASC VATC | — — |
| -40°C to 125°C | 3000 μV | TLV2780ID TLV2781ID | TLV2780IDBV TLV2781IDBV | VASI VATI | TLV2780IP TLV2781IP |
| | 2000 μV | TLV2780AID TLV2781AID | — — | — — | — — |

† This package is available taped and reeled. To order this packaging option, add an **R** suffix to the part number (e.g., TLV2780CDR).

‡ This package is only available taped and reeled. For standard quantities (3,000 pieces per reel), add an **R** suffix (i.e., TLV2780CDBVR). For smaller quantities (250 pieces per mini-reel), add a **T** suffix to the part number (e.g., TLV2780CDBVT).

TLV2782 and TLV2783 AVAILABLE OPTIONS(1)

| T _A | V _{IOmax} AT 25°C | PACKAGED DEVICES | | | | | | |
|----------------|-------------------------------|--------------------------|------------------|--------------|------------------|--------------|-----------------------|-----------------------|
| | | SMALL OUTLINE† (D) | MSOP | | | | PLASTIC DIP (N) | PLASTIC DIP (P) |
| | | | (DGK)† | SYMBOL | (DGS)† | SYMBOL | | |
| 0°C to 70°C | 3000 μV | TLV2782CD TLV2783CD | TLV2782CDGK — | xxTIADL — | — TLV2783CDGS | — xxTIADN | — — | — — |
| -40°C to 125°C | 3000 μV | TLV2782ID TLV2783ID | TLV2782IDGK — | xxTIADM — | — TLV2783IDGS | — xxTIADO | — TLV2783IN | TLV2782IP — |
| | 2000 μV | TLV2782AID TLV2783AID | — — | — — | — — | — — | — — | — — |

† This package is available taped and reeled. To order this packaging option, add an **R** suffix to the part number (e.g., TLV2782CDR).

TLV2784 and TLV2785 AVAILABLE OPTIONS(1)

| T _A | V _{IOmax} AT 25°C | PACKAGED DEVICES | | |
|----------------|-------------------------------|--------------------------|------------------------|----------------------------|
| | | SMALL OUTLINE (D) | PLASTIC DIP (N) | TSSOP† (PW) |
| 0°C to 70°C | 3000 μV | TLV2784CD TLV2785CD | — — | TLV2784CPW TLV2785CPW |
| -40°C to 125°C | 3000 μV | TLV2784ID TLV2785ID | TLV2784IN TLV2785IN | TLV2784IPW TLV2785IPW |
| | 2000 μV | TLV2784AID TLV2785AID | — — | TLV2784AIPW TLV2785AIPW |

† This package is available taped and reeled. To order this packaging option, add an **R** suffix to the part number (e.g., TLV2784CDR).

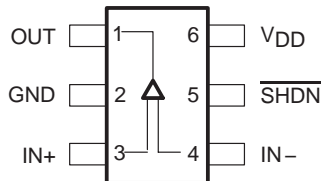
- For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

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TLV278x PACKAGE PINOUTS

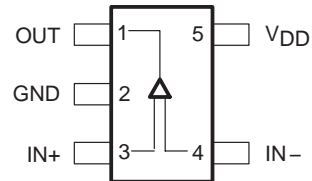
**TLV2780
DBV PACKAGE
(TOP VIEW)**



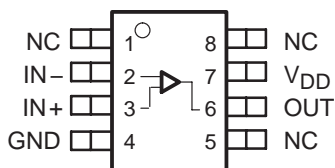
**TLV2780
D OR P PACKAGE
(TOP VIEW)**



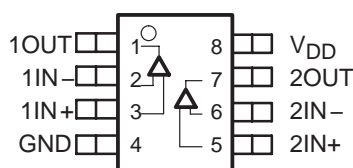
**TLV2781
DBV PACKAGE
(TOP VIEW)**



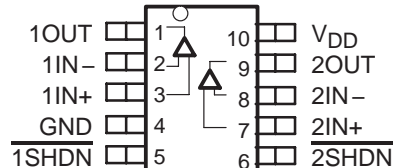
**TLV2781
D OR P PACKAGE
(TOP VIEW)**



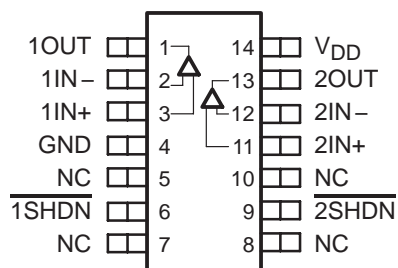
**TLV2782
D, DGK, OR P PACKAGE
(TOP VIEW)**



**TLV2783
DGS PACKAGE
(TOP VIEW)**



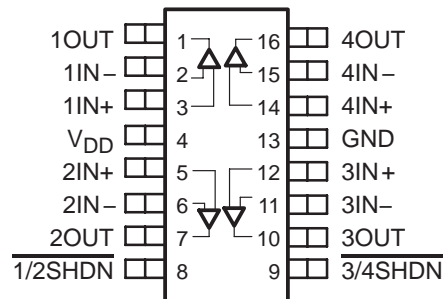
**TLV2783
D OR N PACKAGE
(TOP VIEW)**



**TLV2784
D, N, OR PW PACKAGE
(TOP VIEW)**



**TLV2785
D, N, OR PW PACKAGE
(TOP VIEW)**



NC – No internal connection

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

| | |
|--|------------------------------|
| Supply voltage, V_{DD} (see Note 1) | 4 V |
| Differential input voltage, V_{ID} | $\pm V_{DD}$ |
| Input current, I_I (any input) | ± 10 mA |
| Output current, I_O | ± 10 mA |
| Continuous total power dissipation | See Dissipation Rating Table |
| Operating free-air temperature range, T_A : C-suffix | 0°C to 70°C |
| I-suffix | -40°C to 125°C |
| Maximum junction temperature, T_J | 150°C |
| Storage temperature range, T_{stg} | -65°C to 150°C |
| Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds | 260°C |

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values, except differential voltages, are with respect to GND.

DISSIPATION RATING TABLE

| PACKAGE | θ_{JC} (°C/W) | θ_{JA} (°C/W) | $T_A \leq 25^\circ\text{C}$ POWER RATING | $T_A = 125^\circ\text{C}$ POWER RATING |
|------------|-------------------------|-------------------------|---|---|
| D (8) | 38.3 | 176 | 710 mW | 142 mW |
| D (14) | 26.9 | 122.3 | 1022 mW | 204.4 mW |
| D (16) | 25.7 | 114.7 | 1090 mW | 218 mW |
| DBV (5) | 55 | 324.1 | 385 mW | 77.1 mW |
| DBV (6) | 55 | 294.3 | 425 mW | 85 mW |
| DGK (8) | 54.2 | 259.9 | 481 mW | 96.2 mW |
| DGS (10) | 54.1 | 257.7 | 485 mW | 97 mW |
| N (14, 16) | 32 | 78 | 1600 mW | 320.5 mW |
| P (8) | 41 | 104 | 1200 mW | 240.4 mW |
| PW (14) | 29.3 | 173.6 | 720 mW | 144 mW |
| PW (16) | 28.7 | 161.4 | 774 mW | 154.9 mW |

recommended operating conditions

| | | MIN | MAX | UNIT |
|--|---------------|-------------------------|--------------|------|
| Supply voltage, V_{DD} | Single supply | 1.8 | 3.6 | V |
| | Split supply | ± 0.9 | ± 1.8 | |
| Common-mode input voltage range, V_{ICR} | | -0.2 | $V_{DD}+0.2$ | V |
| Operating free-air temperature, T_A | C-suffix | 0 | 70 | °C |
| | I-suffix | -40 | 125 | |
| Shutdown on/off voltage level‡ | V_{IH} | $V_{DD} < 2.7$ V | $0.75V_{DD}$ | V |
| | | $V_{DD} = 2.7$ to 3.6 V | 2 | |
| | V_{IL} | | 0.6 | |

‡ Relative to GND.

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electrical characteristics at specified free-air temperature, $V_{DD} = 1.8 \text{ V}, 2.7 \text{ V}$ (unless otherwise noted)

dc performance

| PARAMETER | TEST CONDITIONS | | T_A † | MIN | TYP | MAX | UNIT |
|--|--|--|------------|-----|------|------------------------------|---------------|
| V_{IO} Input offset voltage | $V_O = V_{DD}/2,$ $R_L = 2 \text{ k}\Omega,$ $R_S = 50 \Omega$ | TLV278x | 25°C | 250 | 3000 | | μV |
| | | | Full range | | 4500 | | |
| | | TLV278xA | 25°C | 250 | 2000 | | |
| | | | Full range | | 3000 | | |
| α_{VIO} Temperature coefficient of input offset voltage | | | | 8 | | $\mu\text{V}/^\circ\text{C}$ | |
| CMRR Common-mode rejection ratio | $V_{IC} = 0 \text{ to } V_{DD},$ $R_S = 50 \Omega$ | $V_{DD} = 1.8 \text{ V}$ | 25°C | 50 | 76 | | dB |
| | | | Full range | | 50 | | |
| | | $V_{DD} = 2.7 \text{ V}/3.6 \text{ V}$ | 25°C | 55 | 80 | | |
| | | | Full range | | 50 | | |
| | $V_{IC} = 1.2 \text{ V to } V_{DD},$ $R_S = 50 \Omega$ | $V_{DD} = 2.7 \text{ V}/3.6 \text{ V}$ | 25°C | 70 | 100 | | |
| | | | Full range | | 70 | | |
| A_{VD} Large-signal differential voltage amplification | $R_L = 2 \text{ k}\Omega,$ $V_{O(PP)} = 1 \text{ V}$ | $V_{DD} = 1.8 \text{ V}$ | 25°C | 200 | 600 | | V/mV |
| | | | Full range | | 50 | | |
| | | $V_{DD} = 2.7 \text{ V}/3.6 \text{ V}$ | 25°C | 200 | 1000 | | |
| | | | Full range | | 70 | | |

† Full range is 0°C to 70°C for the C-suffix and –40°C to 125°C for the I-suffix. If not specified, full range is –40°C to 125°C.

input characteristics

| PARAMETER | TEST CONDITIONS | T_A † | MIN | TYP | MAX | UNIT |
|--|--|----------|------------|------|-----|------------------|
| I_{IO} Input offset current | $V_O = V_{DD}/2,$ $R_L = 2 \text{ k}\Omega,$ $R_S = 50 \Omega$ | 25°C | | 2.5 | 15 | pA |
| | | TLV278xC | Full range | | 100 | |
| | | TLV278xI | Full range | | 300 | |
| I_{IB} Input bias current | $V_O = V_{DD}/2,$ $R_L = 2 \text{ k}\Omega,$ $R_S = 50 \Omega$ | 25°C | | 2.5 | 15 | pA |
| | | TLV278xC | Full range | | 100 | |
| | | TLV278xI | Full range | | 300 | |
| $r_{i(d)}$ Differential input resistance | | 25°C | | 1000 | | $\text{G}\Omega$ |
| $C_{i(c)}$ Common-mode input capacitance | $f = 1 \text{ kHz}$ | 25°C | | 19 | | pF |

† Full range is 0°C to 70°C for the C-suffix and –40°C to 125°C for the I-suffix. If not specified, full range is –40°C to 125°C.

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electrical characteristics at specified free-air temperature, $V_{DD} = 1.8\text{ V}, 2.7\text{ V}$ (unless otherwise noted) (continued)

output characteristics

| PARAMETER | TEST CONDITIONS | | T_A † | MIN | TYP | MAX | UNIT | |
|---------------------------------------|---|-------------------------|-------------------------|-------------------------|------|-----|------|------|
| V_{OH} High-level output voltage | $I_{OH} = -1\text{ mA}$ | $V_{DD} = 1.8\text{ V}$ | 25°C | 1.7 | 1.77 | | V | |
| | | | Full range | 1.63 | | | | |
| | | $V_{DD} = 2.7\text{ V}$ | 25°C | 2.6 | 2.68 | | | |
| | | | Full range | 2.6 | | | | |
| | | $V_{DD} = 3.6\text{ V}$ | 25°C | | 3.58 | | | |
| | | | $I_{OH} = -5\text{ mA}$ | $V_{DD} = 1.8\text{ V}$ | 25°C | 1.5 | | 1.55 |
| | Full range | | | | 1.46 | | | |
| | $V_{DD} = 2.7\text{ V}$ | 25°C | 2.5 | 2.55 | | | | |
| | | Full range | 2.45 | | | | | |
| $V_{DD} = 3.6\text{ V}$ | | 25°C | | 3.55 | | | | |
| V_{OL} Low-level output voltage | $I_{OL} = 1\text{ mA}$ | | 25°C | | | 70 | mV | |
| | | | Full range | | | 80 | | |
| | $I_{OL} = 5\text{ mA}$ | $V_{DD} = 1.8\text{ V}$ | 25°C | | 180 | 240 | | |
| | | | Full range | | | 290 | | |
| | | $V_{DD} = 2.7\text{ V}$ | 25°C | | 120 | 170 | | |
| | | | Full range | | | 200 | | |
| I_O Output current | $V_{DD} = 1.8\text{ V},$ $V_O = 0.5\text{ V from}$ | Positive rail | 25°C | | | 10 | mA | |
| | | Negative rail | | | | 15 | | |
| | $V_{DD} = 2.7\text{ V},$ $V_O = 0.5\text{ V from}$ | Positive rail | | | | 17 | | |
| | | Negative rail | | | | 23 | | |
| I_{OS} Short-circuit output current | Sourcing | $V_{DD} = 1.8\text{ V}$ | 25°C | | | 13 | mA | |
| | | $V_{DD} = 2.7\text{ V}$ | | | | 35 | | |
| | Sinking | $V_{DD} = 1.8\text{ V}$ | | | | 21 | | |
| | | $V_{DD} = 2.7\text{ V}$ | | | | 45 | | |

† Full range is 0°C to 70°C for the C-suffix and -40°C to 125°C for the I-suffix. If not specified, full range is -40°C to 125°C.

power supply

| PARAMETER | TEST CONDITIONS | | T_A † | MIN | TYP | MAX | UNIT |
|--|--|-----------------------------------|------------|-----|-----|-----|---------------|
| I_{DD} Supply current (per channel) | $V_O = V_{DD}/2,$ | $\overline{\text{SHDN}} = V_{DD}$ | 25°C | | 650 | 770 | μA |
| | | | Full range | | | 820 | |
| k_{SVR} Supply voltage rejection ratio ($\Delta V_{DD} / \Delta V_{IO}$) | $V_{DD} = 1.8\text{ V to } 2.7\text{ V},$ $V_{IC} = V_{DD}/2$ | No load, | 25°C | | 60 | 75 | dB |
| | | | Full range | | | 58 | |
| | $V_{DD} = 2.7\text{ V to } 3.6\text{ V},$ $V_{IC} = V_{DD}/2$ | No load, | 25°C | | 75 | 90 | |
| | | | Full range | | | 70 | |
| | $V_{DD} = 1.8\text{ V to } 3.6\text{ V},$ $V_{IC} = V_{DD}/2$ | No load, | 25°C | | 65 | 80 | |
| | | | Full range | | | 60 | |

† Full range is 0°C to 70°C for the C-suffix and -40°C to 125°C for the I-suffix. If not specified, full range is -40°C to 125°C.

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electrical characteristics at specified free-air temperature, $V_{DD} = 1.8\text{ V}, 2.7\text{ V}$ (unless otherwise noted) (continued)

dynamic performance

| PARAMETER | | TEST CONDITIONS | | T_A † | MIN | TYP | MAX | UNIT |
|-----------|----------------------------------|---|----------------------|-------------------------|------------|------|-----|------------|
| UGBW | Unity gain bandwidth | $R_L = 2\text{ k}\Omega$, | $C_L = 25\text{ pF}$ | 25°C | | 8 | | MHz |
| SR+ | Positive slew rate at unity gain | $V_{O(PP)} = 1\text{ V}$, $R_L = 2\text{ k}\Omega$, $C_L = 50\text{ pF}$ | | $V_{DD} = 1.8\text{ V}$ | 25°C | 3.3 | 4.3 | V/ μ s |
| | | | | | Full range | 3.1 | | |
| | | | | $V_{DD} = 2.7\text{ V}$ | 25°C | 3.8 | 4.8 | |
| | | | | | Full range | 3.5 | | |
| | | | | $V_{DD} = 3.6\text{ V}$ | 25°C | 4 | 5 | |
| | | | | | Full range | 3.6 | | |
| SR- | Negative slew rate at unity gain | $V_{O(PP)} = 1\text{ V}$, $R_L = 2\text{ k}\Omega$, $C_L = 50\text{ pF}$ | | $V_{DD} = 1.8\text{ V}$ | 25°C | 2.1 | 2.8 | |
| | | | | | Full range | 1.89 | | |
| | | | | $V_{DD} = 2.7\text{ V}$ | 25°C | 2.2 | 2.8 | |
| | | | | | Full range | 1.97 | | |
| | | | | $V_{DD} = 3.6\text{ V}$ | 25°C | 3.5 | 4.2 | |
| | | | | | Full range | 3.4 | | |
| ϕ_m | Phase margin | $R_L = 2\text{ k}\Omega$, | $C_L = 25\text{ pF}$ | 25°C | | 58° | | |
| | Gain margin | | | | | 8 | | dB |
| t_s | Settling time | $V_{DD} = 1.8\text{ V}$, $V_{(STEP)PP} = 1\text{ V}$, $A_V = -1$, $C_L = 10\text{ pF}$, $R_L = 2\text{ k}\Omega$ | | 25°C | 0.1% | 1.7 | | μ s |
| | | | | | 0.01% | 2.8 | | |
| | | | | | 0.1% | 1.7 | | |
| | | | | | 0.01% | 2.4 | | |

† Full range is 0°C to 70°C for the C-suffix and -40°C to 125°C for the I-suffix. If not specified, full range is -40°C to 125°C.

noise/distortion performance

| PARAMETER | | TEST CONDITIONS | | T_A | MIN | TYP | MAX | UNIT |
|-----------|--------------------------------------|---|---------------------|-------|-----|--------|-----|------------------------|
| THD + N | Total harmonic distortion plus noise | $V_{O(PP)} = V_{DD}/2$, $R_L = 2\text{ k}\Omega$, $f = 10\text{ kHz}$ | $A_V = 1$ | 25°C | | 0.055% | | |
| | | | $A_V = 10$ | | | 0.08% | | |
| | | | $A_V = 100$ | | | 0.45% | | |
| V_n | Equivalent input noise voltage | $f = 1\text{ kHz}$ | $f = 10\text{ kHz}$ | 25°C | | 18 | | nV/ $\sqrt{\text{Hz}}$ |
| | | | | | | 9 | | |
| I_n | Equivalent input noise current | $f = 1\text{ kHz}$ | | 25°C | | 0.9 | | fA/ $\sqrt{\text{Hz}}$ |

shutdown characteristics

| PARAMETER | | TEST CONDITIONS | T_A † | MIN | TYP | MAX | UNIT |
|----------------|--|---------------------------------------|------------|-----|------|------|------|
| $I_{DD(SHDN)}$ | Supply current, per channel in shutdown mode (TLV2780, TLV2783, TLV2785) | $\overline{\text{SHDN}} = 0\text{ V}$ | 25°C | 900 | 1400 | | nA |
| | | | Full range | | | 1700 | |
| $t_{(on)}$ | Amplifier turnon time‡ | $R_L = 2\text{ k}\Omega$ | 25°C | | 800 | | ns |
| $t_{(off)}$ | Amplifier turnoff time‡ | $R_L = 2\text{ k}\Omega$ | | | 200 | | |

† Full range is 0°C to 70°C for the C-suffix and -40°C to 125°C for the I-suffix. If not specified, full range is -40°C to 125°C.

‡ Disable time and enable time are defined as the interval between application of the logic signal to $\overline{\text{SHDN}}$ and the point at which the supply current has reached half its final value.

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TYPICAL CHARACTERISTICS

Table of Graphs

| | | | FIGURE |
|----------------|--|------------------------------|---------------|
| V_{IO} | Input offset voltage | vs Common-mode input voltage | 1, 2 |
| CMRR | Common-mode rejection ratio | vs Frequency | 3 |
| V_{OH} | High-level output voltage | vs High-level output current | 4, 6 |
| V_{OL} | Low-level output voltage | vs Low-level output current | 5, 7 |
| $V_{O(PP)}$ | Maximum peak-to-peak output voltage | vs Frequency | 8 |
| Z_o | Output impedance | vs Frequency | 9 |
| I_{DD} | Supply current | vs Supply voltage | 10 |
| I_{DD} | Supply current | vs Free-air temperature | 11 |
| PSRR | Power supply rejection ratio | vs Frequency | 12 |
| A_{VD} | Differential voltage amplification & phase | vs Frequency | 13 |
| | Gain-bandwidth product | vs Free-air temperature | 14 |
| SR | Slew rate | vs Supply voltage | 15 |
| | | vs Free-air temperature | 16, 17 |
| ϕ_m | Phase margin | vs Load capacitance | 18 |
| V_n | Equivalent input noise voltage | vs Frequency | 19 |
| | Voltage-follower large-signal pulse response | vs Time | 20 |
| | Voltage-follower small-signal pulse response | vs Time | 21 |
| | Inverting large-signal pulse response | vs Time | 22 |
| | Inverting small-signal pulse response | vs Time | 23 |
| | Crosstalk | vs Frequency | 24 |
| | Shutdown forward & reverse isolation | vs Frequency | 25 |
| $I_{DD(SHDN)}$ | Shutdown supply current | vs Free-air temperature | 26 |
| $I_{DD(SHDN)}$ | Shutdown supply current | vs Supply voltage | 27 |
| $I_{DD(SHDN)}$ | Shutdown supply current/output voltage | vs Time | 28 |

TLV2780, TLV2781, TLV2782, TLV2783, TLV2784, TLV2785, TLV278xA FAMILY OF 1.8 V HIGH-SPEED RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS



Figure 1

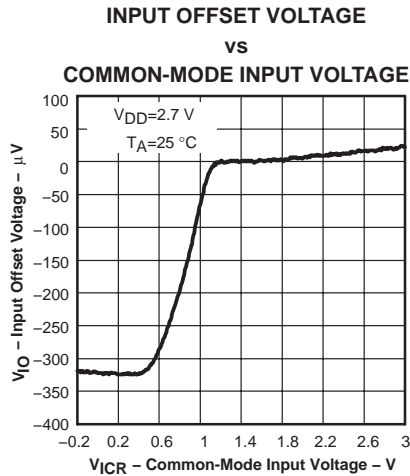


Figure 2

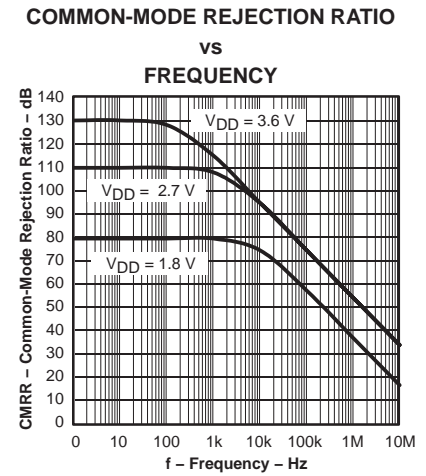


Figure 3



Figure 4

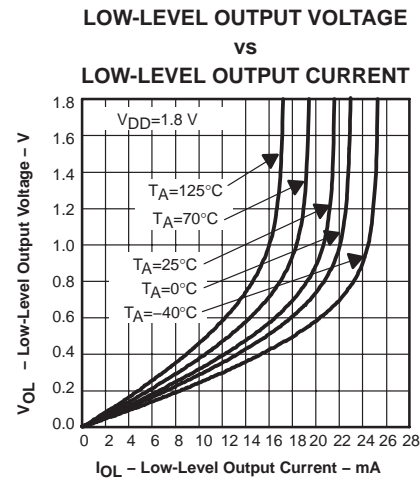


Figure 5

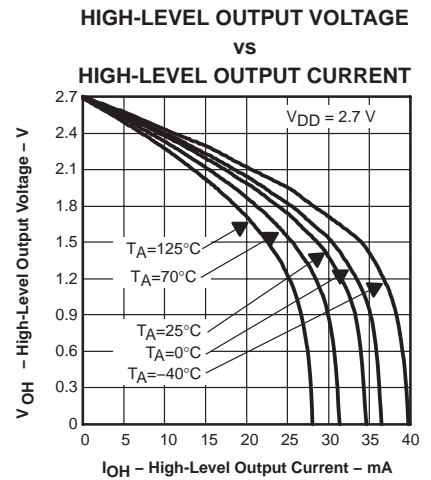


Figure 6

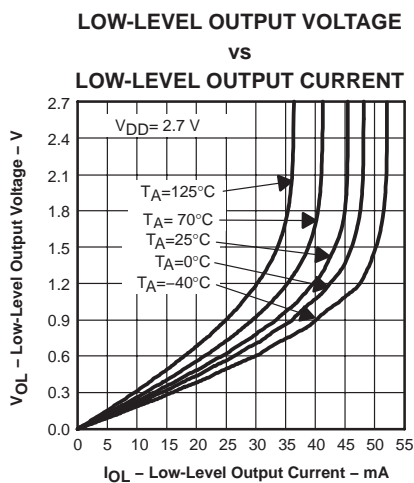


Figure 7

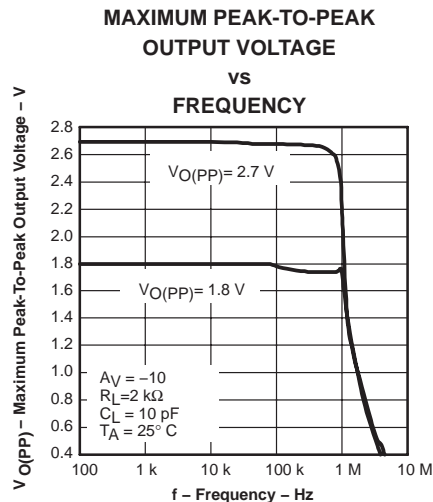


Figure 8

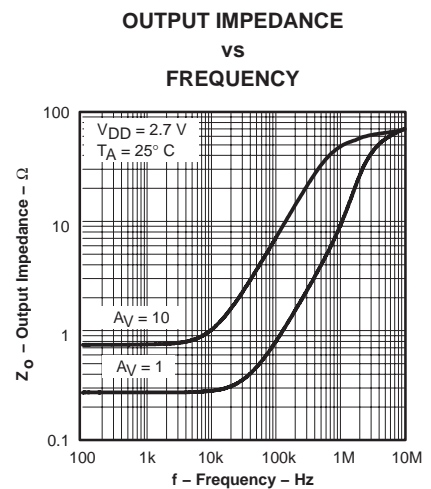


Figure 9

TLV2780, TLV2781, TLV2782, TLV2783, TLV2784, TLV2785, TLV278xA FAMILY OF 1.8 V HIGH-SPEED RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS

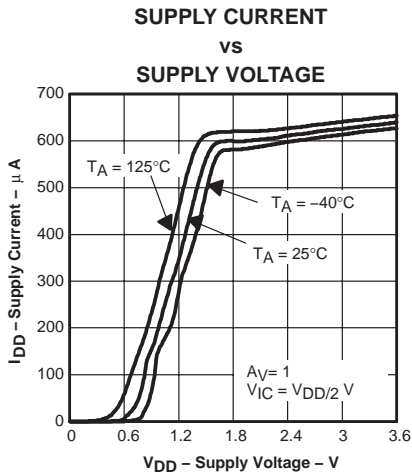


Figure 10

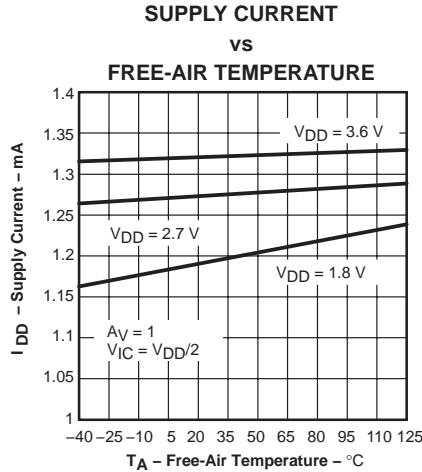


Figure 11

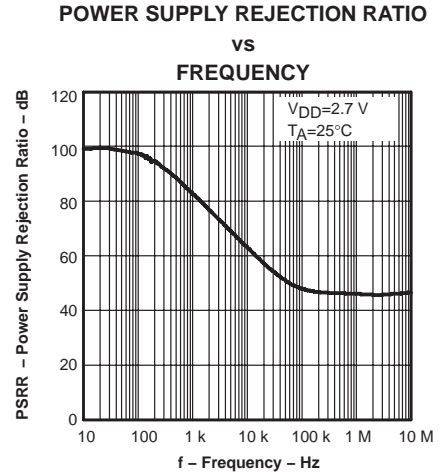


Figure 12

DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE



Figure 13

GAIN-BANDWIDTH PRODUCT

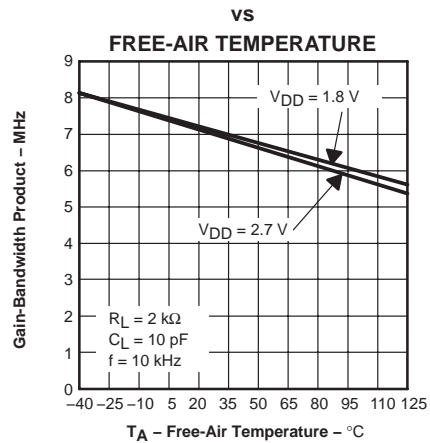


Figure 14

SLEW RATE

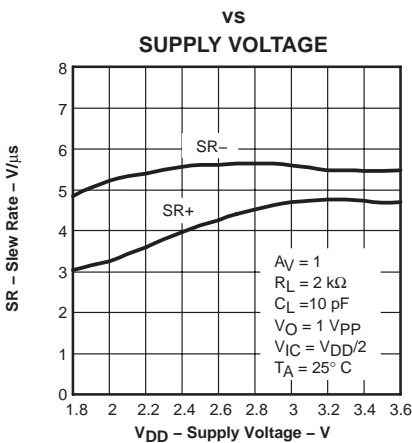


Figure 15

SLEW RATE

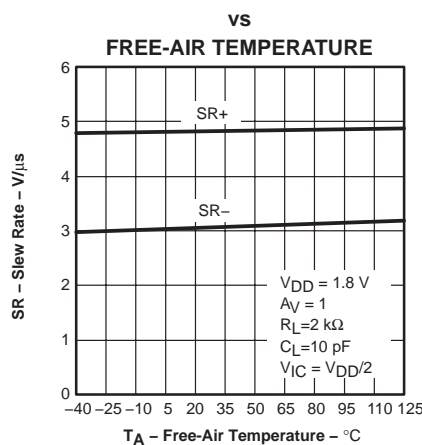


Figure 16

SLEW RATE

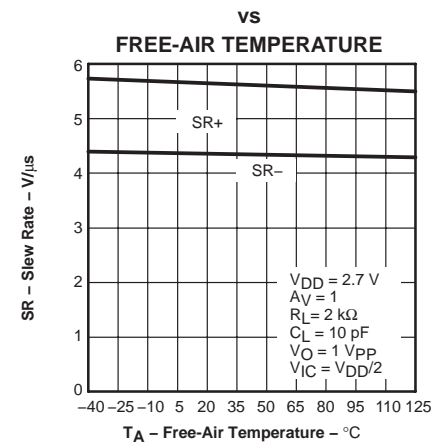


Figure 17

TLV2780, TLV2781, TLV2782, TLV2783, TLV2784, TLV2785, TLV278xA FAMILY OF 1.8 V HIGH-SPEED RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS

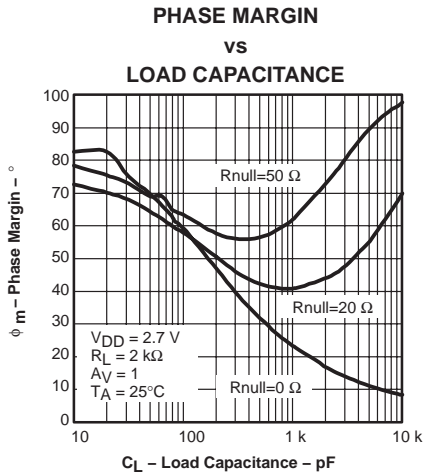


Figure 18

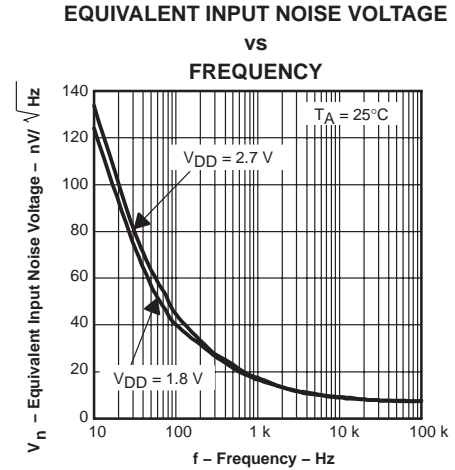


Figure 19

VOLTAGE-FOLLOWER LARGE-SIGNAL PULSE RESPONSE

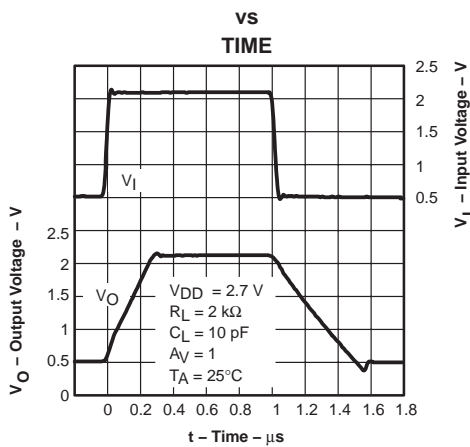


Figure 20

VOLTAGE-FOLLOWER SMALL-SIGNAL PULSE RESPONSE

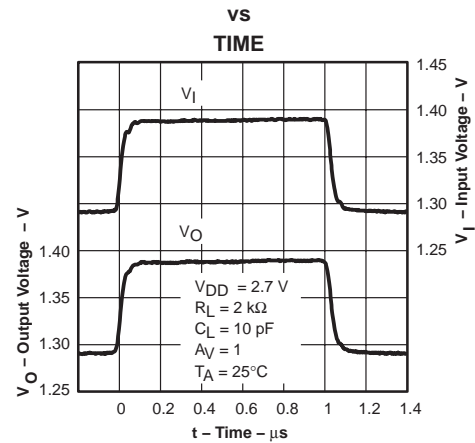


Figure 21

INVERTING LARGE-SIGNAL PULSE RESPONSE

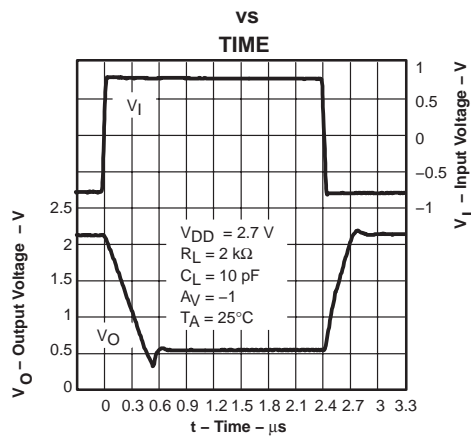


Figure 22

INVERTING SMALL-SIGNAL PULSE RESPONSE

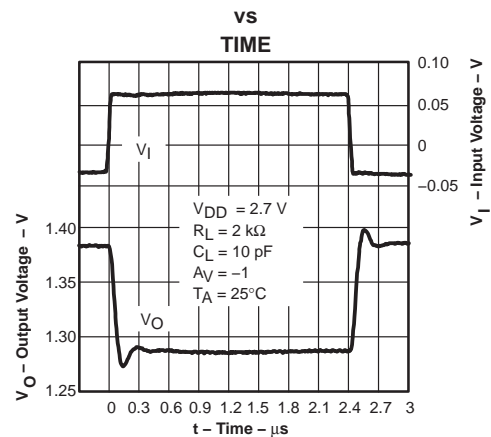
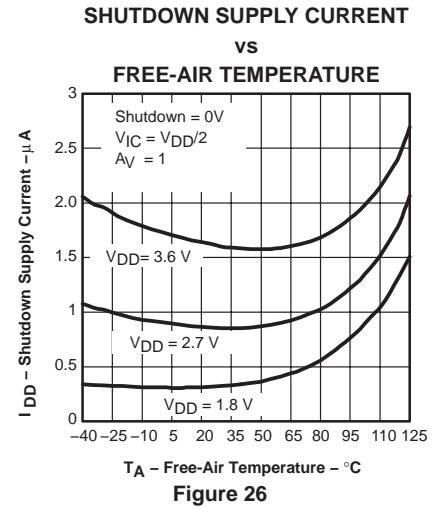
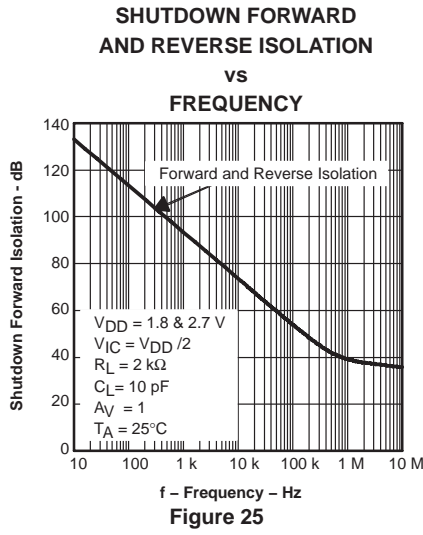
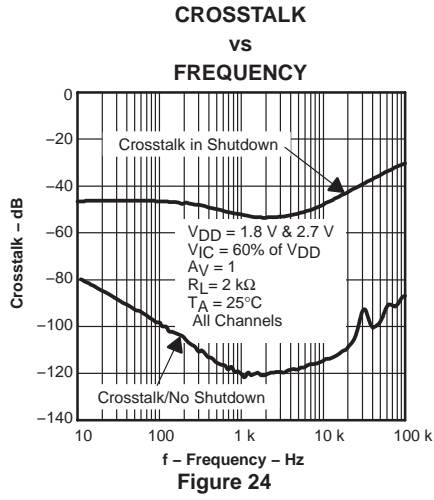


Figure 23

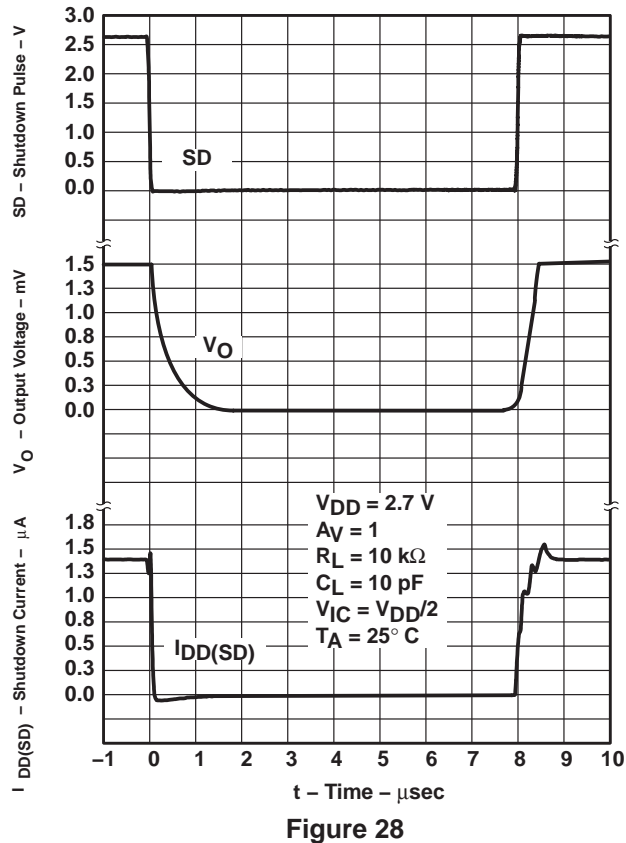
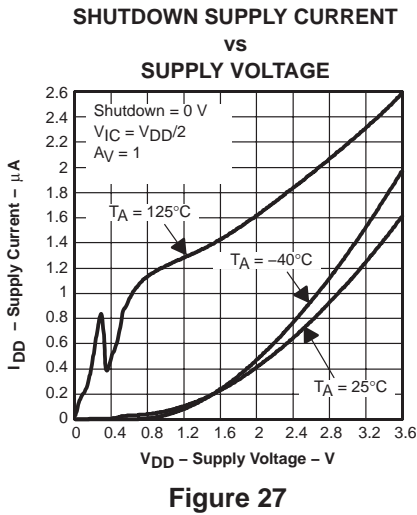
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TYPICAL CHARACTERISTICS



SHUTDOWN SUPPLY CURRENT / OUTPUT VOLTAGE vs TIME



PARAMETER MEASUREMENT INFORMATION

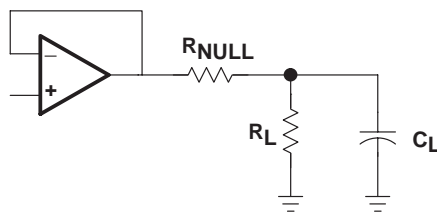


Figure 29

APPLICATION INFORMATION

driving a capacitive load

When the amplifier is configured in this manner, capacitive loading directly on the output will decrease the device's phase margin leading to high frequency ringing or oscillations. Therefore, for capacitive loads of greater than 10 pF, it is recommended that a resistor be placed in series (R_{NULL}) with the output of the amplifier, as shown in Figure 30.

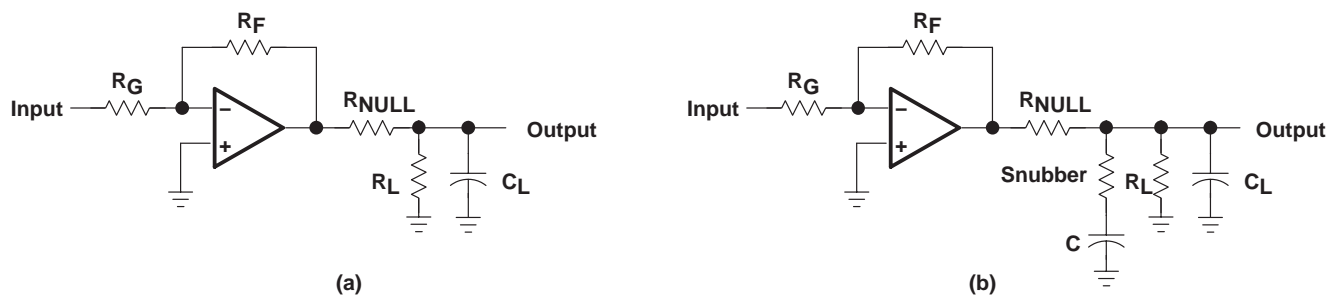


Figure 30. Driving a Capacitive Load

offset voltage

The output offset voltage, (V_{OO}) is the sum of the input offset voltage (V_{IO}) and both input bias currents (I_{IB}) times the corresponding gains. The following schematic and formula can be used to calculate the output offset voltage:

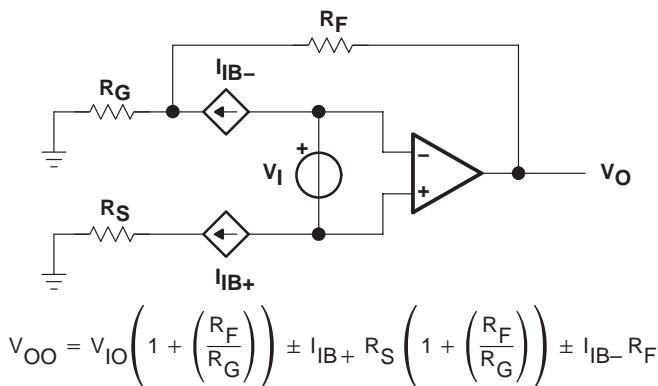


Figure 31. Output Offset Voltage Model

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APPLICATION INFORMATION

general configurations

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to accomplish this is to place an RC filter at the noninverting terminal of the amplifier (see Figure 32).

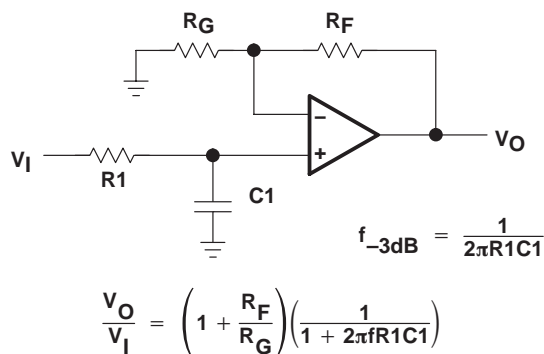


Figure 32. Single-Pole Low-Pass Filter

If even more attenuation is needed, a multiple pole filter is required. The Sallen-Key filter can be used for this task. For best results, the amplifier should have a bandwidth that is 8 to 10 times the filter frequency bandwidth. Failure to do this can result in phase shift of the amplifier.

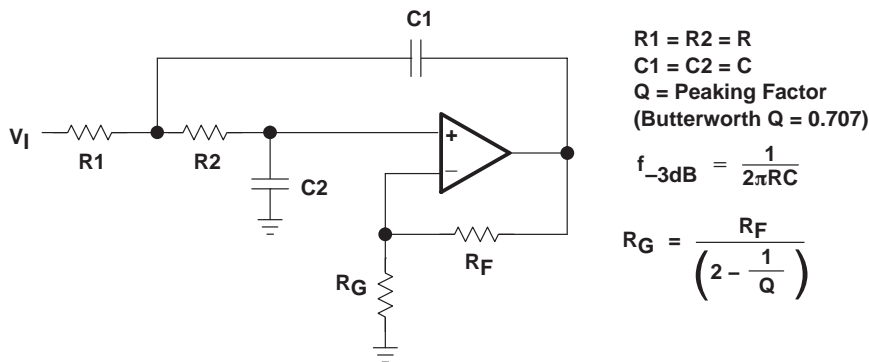


Figure 33. 2-Pole Low-Pass Sallen-Key Filter

APPLICATION INFORMATION

circuit layout considerations

To achieve the levels of high performance of the TLV278x, follow proper printed-circuit board design techniques. A general set of guidelines is given in the following.

- Ground planes – It is highly recommended that a ground plane be used on the board to provide all components with a low inductive ground connection. However, in the areas of the amplifier inputs and output, the ground plane can be removed to minimize the stray capacitance.
- Proper power supply decoupling – Use a 6.8- μ F tantalum capacitor in parallel with a 0.1- μ F ceramic capacitor on each supply terminal. It may be possible to share the tantalum among several amplifiers depending on the application, but a 0.1- μ F ceramic capacitor should always be used on the supply terminal of every amplifier. In addition, the 0.1- μ F capacitor should be placed as close as possible to the supply terminal. As this distance increases, the inductance in the connecting trace makes the capacitor less effective. The designer should strive for distances of less than 0.1 inches between the device power terminals and the ceramic capacitors.
- Sockets – Sockets can be used but are not recommended. The additional lead inductance in the socket pins will often lead to stability problems. Surface-mount packages soldered directly to the printed-circuit board is the best implementation.
- Short trace runs/compact part placements – Optimum high performance is achieved when stray series inductance has been minimized. To realize this, the circuit layout should be made as compact as possible, thereby minimizing the length of all trace runs. Particular attention should be paid to the inverting input of the amplifier. Its length should be kept as short as possible. This will help to minimize stray capacitance at the input of the amplifier.
- Surface-mount passive components – Using surface-mount passive components is recommended for high performance amplifier circuits for several reasons. First, because of the extremely low lead inductance of surface-mount components, the problem with stray series inductance is greatly reduced. Second, the small size of surface-mount components naturally leads to a more compact layout, thereby minimizing both stray inductance and capacitance. If leaded components are used, it is recommended that the lead lengths be kept as short as possible.

shutdown function

Three members of the TLV278x family (TLV2780/3/5) have a shutdown terminal for conserving battery life in portable applications. When the shutdown terminal is tied low, the supply current is reduced to 900 nA/channel, the amplifier is disabled, and the outputs are placed in a high impedance mode. To enable the amplifier, the shutdown terminal can either be left floating or pulled high. When the shutdown terminal is left floating, care should be taken to ensure that parasitic leakage current at the shutdown terminal does not inadvertently place the operational amplifier into shutdown.

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APPLICATION INFORMATION

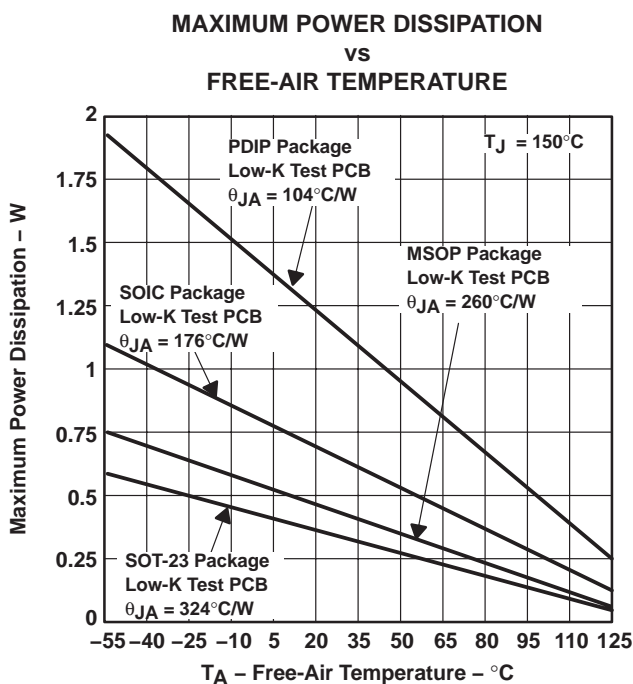
general power dissipation considerations

For a given θ_{JA} , the maximum power dissipation is shown in Figure 34 and is calculated by the following formula:

$$P_D = \left(\frac{T_{MAX} - T_A}{\theta_{JA}} \right)$$

Where:

- P_D = Maximum power dissipation of TLV278x IC (watts)
- T_{MAX} = Absolute maximum junction temperature (150°C)
- T_A = Free-ambient air temperature (°C)
- θ_{JA} = $\theta_{JC} + \theta_{CA}$
- θ_{JC} = Thermal coefficient from junction to case
- θ_{CA} = Thermal coefficient from case to ambient air (°C/W)



NOTE A: Results are with no air flow and using JEDEC Standard Low-K test PCB.

Figure 34. Maximum Power Dissipation vs Free-Air Temperature

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|-----------------|------|-------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|-------------------------|
| TLV2780CDBVR | ACTIVE | SOT-23 | DBV | 6 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | VASC | Samples |
| TLV2780CDBVT | LIFEBUY | SOT-23 | DBV | 6 | 250 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | VASC | |
| TLV2780IDBVR | ACTIVE | SOT-23 | DBV | 6 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | VASI | Samples |
| TLV2780IDBVT | ACTIVE | SOT-23 | DBV | 6 | 250 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | VASI | Samples |
| TLV2780IDR | ACTIVE | SOIC | D | 8 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | T2780I | Samples |
| TLV2781CDBVR | ACTIVE | SOT-23 | DBV | 5 | 3000 | RoHS & Green | NIPDAU SN | Level-1-260C-UNLIM | 0 to 70 | VATC | Samples |
| TLV2781CDBVT | ACTIVE | SOT-23 | DBV | 5 | 250 | RoHS & Green | NIPDAU SN | Level-1-260C-UNLIM | 0 to 70 | VATC | Samples |
| TLV2781ID | ACTIVE | SOIC | D | 8 | 75 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | T2781I | Samples |
| TLV2781IDBVR | ACTIVE | SOT-23 | DBV | 5 | 3000 | RoHS & Green | NIPDAU SN | Level-1-260C-UNLIM | -40 to 125 | VATI | Samples |
| TLV2781IDBVT | ACTIVE | SOT-23 | DBV | 5 | 250 | RoHS & Green | NIPDAU SN | Level-1-260C-UNLIM | -40 to 125 | VATI | Samples |
| TLV2781IDR | ACTIVE | SOIC | D | 8 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | T2781I | Samples |
| TLV2782CD | ACTIVE | SOIC | D | 8 | 75 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | 2782C | Samples |
| TLV2782CDG4 | ACTIVE | SOIC | D | 8 | 75 | TBD | Call TI | Call TI | 0 to 70 | | Samples |
| TLV2782CDGK | ACTIVE | VSSOP | DGK | 8 | 80 | RoHS & Green | NIPDAU NIPDAUAG | Level-1-260C-UNLIM | 0 to 70 | ADL | Samples |
| TLV2782CDGKR | ACTIVE | VSSOP | DGK | 8 | 2500 | RoHS & Green | NIPDAU NIPDAUAG | Level-1-260C-UNLIM | 0 to 70 | ADL | Samples |
| TLV2782CDR | ACTIVE | SOIC | D | 8 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | 2782C | Samples |
| TLV2782ID | OBSOLETE | SOIC | D | 8 | | TBD | Call TI | Call TI | -40 to 125 | 2782I | |
| TLV2782IDGK | ACTIVE | VSSOP | DGK | 8 | 80 | RoHS & Green | NIPDAU NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | ADM | Samples |
| TLV2782IDGKR | ACTIVE | VSSOP | DGK | 8 | 2500 | RoHS & Green | NIPDAU NIPDAUAG | Level-1-260C-UNLIM | -40 to 125 | ADM | Samples |
| TLV2782IDR | ACTIVE | SOIC | D | 8 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | 2782I | Samples |

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|-----------------|------|-------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|-------------------------|
| TLV2782IP | ACTIVE | PDIP | P | 8 | 50 | RoHS & Green | NIPDAU | N / A for Pkg Type | -40 to 125 | TLV2782IP | Samples |
| TLV2783IDGS | OBSOLETE | VSSOP | DGS | 10 | | TBD | Call TI | Call TI | -40 to 125 | ADO | |
| TLV2783IDGSR | ACTIVE | VSSOP | DGS | 10 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | ADO | Samples |
| TLV2783IN | ACTIVE | PDIP | N | 14 | 25 | RoHS & Green | NIPDAU | N / A for Pkg Type | -40 to 125 | TLV2783I | Samples |
| TLV2784AID | ACTIVE | SOIC | D | 14 | 50 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | 2784AI | Samples |
| TLV2784AIDR | ACTIVE | SOIC | D | 14 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | 2784AI | Samples |
| TLV2784CPWR | ACTIVE | TSSOP | PW | 14 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | 2784C | Samples |
| TLV2784ID | OBSOLETE | SOIC | D | 14 | | TBD | Call TI | Call TI | -40 to 125 | TLV2784I | |
| TLV2784IDR | ACTIVE | SOIC | D | 14 | 2500 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | TLV2784I | Samples |
| TLV2784IPW | ACTIVE | TSSOP | PW | 14 | 90 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | 2784I | Samples |
| TLV2784IPWR | ACTIVE | TSSOP | PW | 14 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | 2784I | Samples |
| TLV2785AID | ACTIVE | SOIC | D | 16 | 40 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | 2785AI | Samples |
| TLV2785CPWR | ACTIVE | TSSOP | PW | 16 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | 2785C | Samples |
| TLV2785IN | ACTIVE | PDIP | N | 16 | 25 | RoHS & Green | NIPDAU | N / A for Pkg Type | -40 to 125 | TLV2785I | Samples |
| TLV2785IPWR | ACTIVE | TSSOP | PW | 16 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | 2785I | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of ≤ 1000 ppm threshold. Antimony trioxide based flame retardants must also meet the ≤ 1000 ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TLV2780CDBVR | SOT-23 | DBV | 6 | 3000 | 180.0 | 8.4 | 3.2 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| TLV2780CDBVR | SOT-23 | DBV | 6 | 3000 | 180.0 | 9.0 | 3.15 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| TLV2780CDBVT | SOT-23 | DBV | 6 | 250 | 180.0 | 9.0 | 3.15 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| TLV2780IDBVR | SOT-23 | DBV | 6 | 3000 | 180.0 | 8.4 | 3.2 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| TLV2780IDBVR | SOT-23 | DBV | 6 | 3000 | 180.0 | 9.0 | 3.15 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| TLV2780IDBVT | SOT-23 | DBV | 6 | 250 | 180.0 | 9.0 | 3.15 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| TLV2780IDBVT | SOT-23 | DBV | 6 | 250 | 180.0 | 8.4 | 3.2 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| TLV2780IDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| TLV2781CDBVR | SOT-23 | DBV | 5 | 3000 | 180.0 | 9.0 | 3.15 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| TLV2781CDBVR | SOT-23 | DBV | 5 | 3000 | 180.0 | 8.4 | 3.2 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| TLV2781CDBVT | SOT-23 | DBV | 5 | 250 | 180.0 | 8.4 | 3.2 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| TLV2781CDBVT | SOT-23 | DBV | 5 | 250 | 180.0 | 9.0 | 3.15 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| TLV2781IDBVR | SOT-23 | DBV | 5 | 3000 | 180.0 | 8.4 | 3.2 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| TLV2781IDBVR | SOT-23 | DBV | 5 | 3000 | 180.0 | 9.0 | 3.15 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| TLV2781IDBVT | SOT-23 | DBV | 5 | 250 | 180.0 | 8.4 | 3.2 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| TLV2781IDBVT | SOT-23 | DBV | 5 | 250 | 180.0 | 9.0 | 3.15 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |

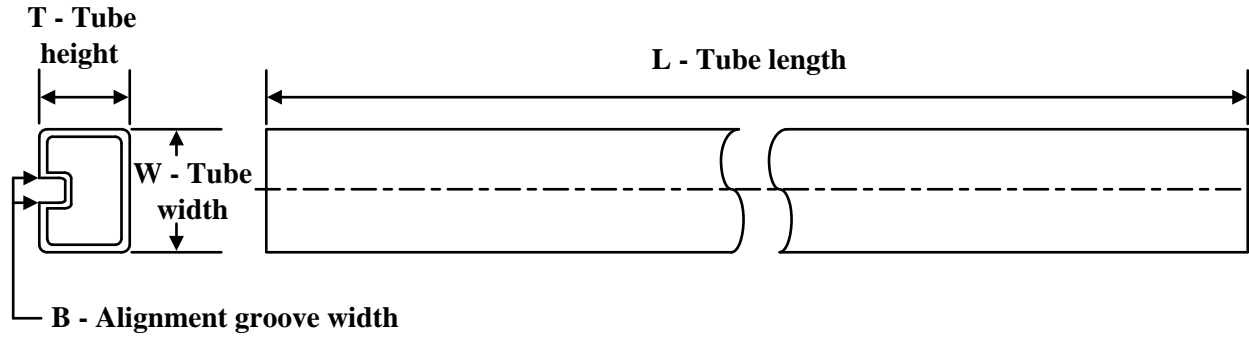
| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TLV2781IDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| TLV2782CDGKR | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| TLV2782CDGKR | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| TLV2782CDGKR | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| TLV2782CDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| TLV2782IDGKR | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| TLV2782IDGKR | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| TLV2782IDGKR | VSSOP | DGK | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| TLV2782IDR | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.4 | 5.2 | 2.1 | 8.0 | 12.0 | Q1 |
| TLV2783IDGSR | VSSOP | DGS | 10 | 2500 | 330.0 | 12.4 | 5.3 | 3.4 | 1.4 | 8.0 | 12.0 | Q1 |
| TLV2784AIDR | SOIC | D | 14 | 2500 | 330.0 | 16.4 | 6.5 | 9.0 | 2.1 | 8.0 | 16.0 | Q1 |
| TLV2784CPWR | TSSOP | PW | 14 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| TLV2784CPWR | TSSOP | PW | 14 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| TLV2784IDR | SOIC | D | 14 | 2500 | 330.0 | 16.4 | 6.5 | 9.0 | 2.1 | 8.0 | 16.0 | Q1 |
| TLV2784IDR | SOIC | D | 14 | 2500 | 330.0 | 16.4 | 6.5 | 9.0 | 2.1 | 8.0 | 16.0 | Q1 |
| TLV2784IPWR | TSSOP | PW | 14 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| TLV2784IPWR | TSSOP | PW | 14 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| TLV2785CPWR | TSSOP | PW | 16 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| TLV2785IPWR | TSSOP | PW | 16 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TLV2780CDBVR | SOT-23 | DBV | 6 | 3000 | 210.0 | 185.0 | 35.0 |
| TLV2780CDBVR | SOT-23 | DBV | 6 | 3000 | 182.0 | 182.0 | 20.0 |
| TLV2780CDBVT | SOT-23 | DBV | 6 | 250 | 182.0 | 182.0 | 20.0 |
| TLV2780IDBVR | SOT-23 | DBV | 6 | 3000 | 210.0 | 185.0 | 35.0 |
| TLV2780IDBVR | SOT-23 | DBV | 6 | 3000 | 182.0 | 182.0 | 20.0 |
| TLV2780IDBVT | SOT-23 | DBV | 6 | 250 | 182.0 | 182.0 | 20.0 |
| TLV2780IDBVT | SOT-23 | DBV | 6 | 250 | 210.0 | 185.0 | 35.0 |
| TLV2780IDR | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| TLV2781CDBVR | SOT-23 | DBV | 5 | 3000 | 182.0 | 182.0 | 20.0 |
| TLV2781CDBVR | SOT-23 | DBV | 5 | 3000 | 210.0 | 185.0 | 35.0 |
| TLV2781CDBVT | SOT-23 | DBV | 5 | 250 | 210.0 | 185.0 | 35.0 |
| TLV2781CDBVT | SOT-23 | DBV | 5 | 250 | 182.0 | 182.0 | 20.0 |
| TLV2781IDBVR | SOT-23 | DBV | 5 | 3000 | 210.0 | 185.0 | 35.0 |
| TLV2781IDBVR | SOT-23 | DBV | 5 | 3000 | 182.0 | 182.0 | 20.0 |
| TLV2781IDBVT | SOT-23 | DBV | 5 | 250 | 210.0 | 185.0 | 35.0 |
| TLV2781IDBVT | SOT-23 | DBV | 5 | 250 | 182.0 | 182.0 | 20.0 |
| TLV2781IDR | SOIC | D | 8 | 2500 | 340.5 | 338.1 | 20.6 |
| TLV2782CDGKR | VSSOP | DGK | 8 | 2500 | 353.0 | 353.0 | 32.0 |

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TLV2782CDGKR | VSSOP | DGK | 8 | 2500 | 364.0 | 364.0 | 27.0 |
| TLV2782CDGKR | VSSOP | DGK | 8 | 2500 | 358.0 | 335.0 | 35.0 |
| TLV2782CDR | SOIC | D | 8 | 2500 | 353.0 | 353.0 | 32.0 |
| TLV2782IDGKR | VSSOP | DGK | 8 | 2500 | 358.0 | 335.0 | 35.0 |
| TLV2782IDGKR | VSSOP | DGK | 8 | 2500 | 364.0 | 364.0 | 27.0 |
| TLV2782IDGKR | VSSOP | DGK | 8 | 2500 | 353.0 | 353.0 | 32.0 |
| TLV2782IDR | SOIC | D | 8 | 2500 | 353.0 | 353.0 | 32.0 |
| TLV2783IDGSR | VSSOP | DGS | 10 | 2500 | 358.0 | 335.0 | 35.0 |
| TLV2784AIDR | SOIC | D | 14 | 2500 | 350.0 | 350.0 | 43.0 |
| TLV2784CPWR | TSSOP | PW | 14 | 2000 | 353.0 | 353.0 | 32.0 |
| TLV2784CPWR | TSSOP | PW | 14 | 2000 | 356.0 | 356.0 | 35.0 |
| TLV2784IDR | SOIC | D | 14 | 2500 | 353.0 | 353.0 | 32.0 |
| TLV2784IDR | SOIC | D | 14 | 2500 | 350.0 | 350.0 | 43.0 |
| TLV2784IPWR | TSSOP | PW | 14 | 2000 | 356.0 | 356.0 | 35.0 |
| TLV2784IPWR | TSSOP | PW | 14 | 2000 | 353.0 | 353.0 | 32.0 |
| TLV2785CPWR | TSSOP | PW | 16 | 2000 | 356.0 | 356.0 | 35.0 |
| TLV2785IPWR | TSSOP | PW | 16 | 2000 | 356.0 | 356.0 | 35.0 |

TUBE


*All dimensions are nominal

| Device | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (μm) | B (mm) |
|-------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| TLV2781ID | D | SOIC | 8 | 75 | 505.46 | 6.76 | 3810 | 4 |
| TLV2781ID | D | SOIC | 8 | 75 | 507 | 8 | 3940 | 4.32 |
| TLV2782CD | D | SOIC | 8 | 75 | 505.46 | 6.76 | 3810 | 4 |
| TLV2782CD | D | SOIC | 8 | 75 | 507 | 8 | 3940 | 4.32 |
| TLV2782CDGK | DGK | VSSOP | 8 | 80 | 330 | 6.55 | 500 | 2.88 |
| TLV2782IDGK | DGK | VSSOP | 8 | 80 | 330 | 6.55 | 500 | 2.88 |
| TLV2782IP | P | PDIP | 8 | 50 | 506 | 13.97 | 11230 | 4.32 |
| TLV2783IN | N | PDIP | 14 | 25 | 506 | 13.97 | 11230 | 4.32 |
| TLV2784AID | D | SOIC | 14 | 50 | 505.46 | 6.76 | 3810 | 4 |
| TLV2784IPW | PW | TSSOP | 14 | 90 | 530 | 10.2 | 3600 | 3.5 |
| TLV2785AID | D | SOIC | 16 | 40 | 505.46 | 6.76 | 3810 | 4 |
| TLV2785IN | N | PDIP | 16 | 25 | 506 | 13.97 | 11230 | 4.32 |

DGS0010A



PACKAGE OUTLINE

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



4221984/A 05/2015

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187, variation BA.

EXAMPLE BOARD LAYOUT

DGS0010A

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
SCALE:10X



SOLDER MASK DETAILS
NOT TO SCALE

4221984/A 05/2015

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DGS0010A

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:10X

4221984/A 05/2015

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - $\triangle C$ Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 - $\triangle D$ Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AB.

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 -  Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
 -  Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
 - E. Falls within JEDEC MO-153

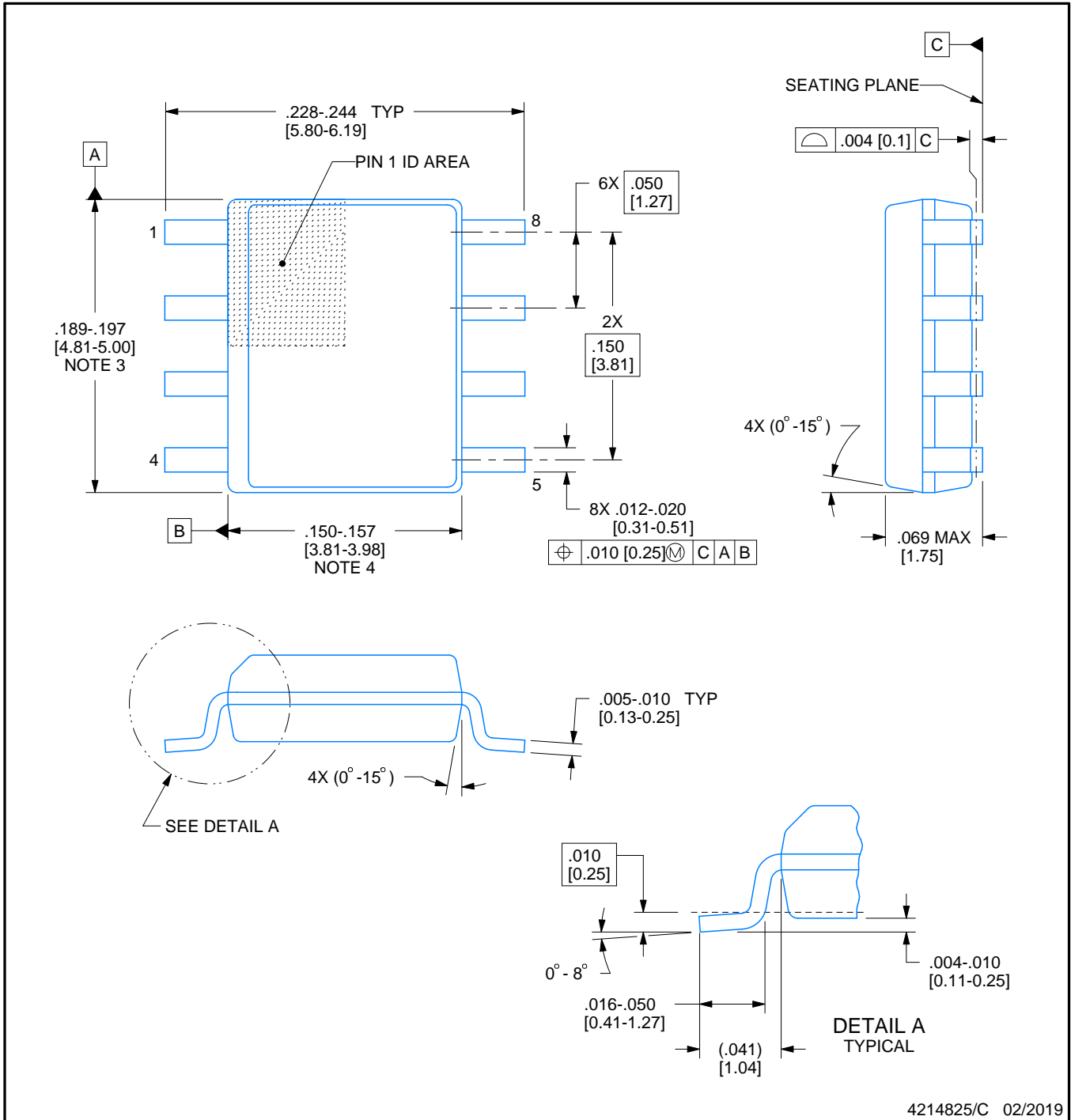


D0008A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed $.006$ [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
 EXPOSED METAL SHOWN
 SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001 variation BA.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - $\triangle C$ Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
 - $\triangle D$ The 20 pin end lead shoulder width is a vendor option, either half or full width.

4040049/E 12/2002



DBV0006A

PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



4214840/G 08/2024

NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
- Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.
- Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- Reference JEDEC MO-178.

EXAMPLE BOARD LAYOUT

DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214840/G 08/2024

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214840/G 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

EXAMPLE BOARD LAYOUT

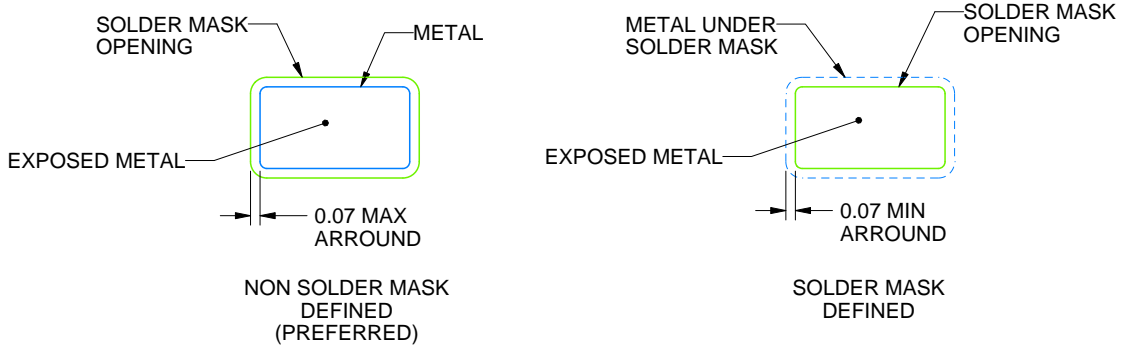
DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

DGK0008A



PACKAGE OUTLINE

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



4214862/A 04/2023

NOTES:

PowerPAD is a trademark of Texas Instruments.

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

EXAMPLE BOARD LAYOUT

DGK0008A

™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X



4214862/A 04/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

EXAMPLE STENCIL DESIGN

DGK0008A

™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
SCALE: 15X

4214862/A 04/2023

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AC.



4220204/A 02/2017

EXAMPLE BOARD LAYOUT

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



4220204/A 02/2017

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220204/A 02/2017

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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